Ordering number :EN4338A



FC808

Silicon Epitaxial Plannar Type

High-Speed Switching Composite Diode (Cathode Common)

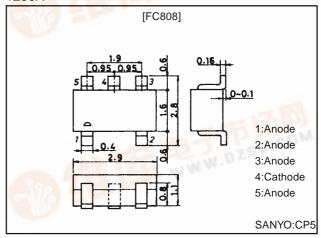
Features

- · Composite type with 4 diodes contained in the CP package currently in use, saving the mounting space greatly.
- \cdot Fast switching speed.

Package Dimensions

unit:mm

1250A



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Peak Reverse Voltage	V _{RM}		85	V
Reverse Voltage	V _R		80	V
Surge Current	I _{FSM}	10ms*	2	Α
Average Rectified Current	I _{O*}		100	mA
Peak Forward Current	I _{FM*}	1 H 195-	300	mA
Allowable Power Dissipation	P*	45 415 LZ	200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg	THE RESERVE TO SERVE THE PARTY OF THE PARTY	-55 to +150	°C

Note) *: Unit rating. The total rating is 150% of the unit rating.

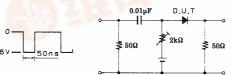
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Falametei			min	typ	max	
Forward Voltage	VF	I _F =10mA		0.72	1.0	V
		I _F =100mA	-121	0.92	1.2	V
Reverse Current	I _R	V _R =50V		07	0.1	μΑ
		V _R =80V	AL AL		0.5	μΑ
Interterminal Capacitance	С	V _R =0V, f=1MHz		4.0	7.0	pF
Reverse Recovery Time	trr	$I_F=10\text{mA}$, $V_R=6V$, $R_L=5\Omega$, $I_{rr}=0.1I_{rp}$			5.0	ns

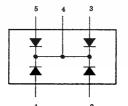
Note) The specifications shown above are for each individual diode.

· Marking:808

Reverse Recovery Time Test Circuit







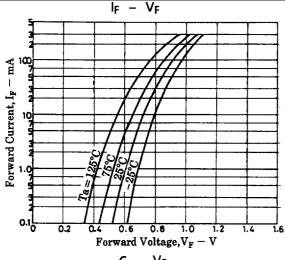
Electrical Connection

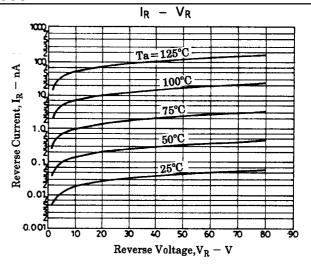
1:Anode

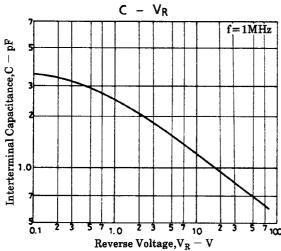
2:Anode 3:Anode

4:Cathode 5:Anode

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